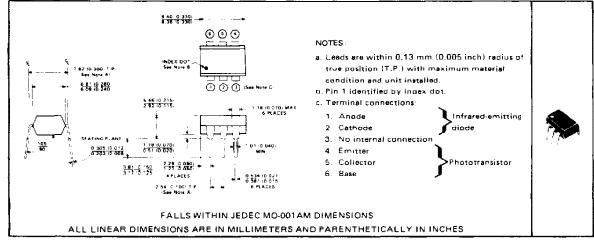
SOOS040 D1607, NOVEMBER 1973-REVISED FEBRUARY 1983

COMPATIBLE WITH STANDARD TTL INTEGRATED CIRCUITS

- Gallium Arsenide Diode Infrared Source Optically Coupled ٠ to a Silicon N-P-N Phototransistor
- High Direct-Current Transfer Ratio ۰
- High-Voltage Electrical Isolation . . . 1.5-kV or 2.5-kV Rating
- Plastic Dual-In-Line Package
- High-Speed Switching: $t_f = 5 \mu s$, $t_f = 5 \mu s$ Typical

mechanical data

The package consists of a gallium arsenide infrared-emitting diode and an n-p-n silicon phototransistor mounted on a 6-lead frame encapsulated within an electrically nonconductive plastic compound. The case will withstand soldering temperature with no deformation and device performance characteristics remain stable when operated in high-humidity conditions. Unit weight is approximately 0.52 grams.



absolute maximum ratings at 25°C free-air temperature (unless otherwise noted)

Input-to-Output Voltage: TIL111											. :	±1.5 k)
TIL114, TIL116, TIL117											. :	±2.5 k'
Collector Base Voltage												70
Collector Emitter Voltage (See Note 1)										• •		. 30
mitter-Collector Voltage												. 7
mitter Base Voltage												. 7
Input-Diode Reverse Voltage									÷			. 3
Input Diode Continuous Forward Current at (or below) 25°C Free	Air Te	mpe	ratu	re (l	See I	Note	e 2)					100 m
Input Diode Continuous Forward Current at (or below) 25°C Free Continuous Power Dissipation at (or below) 25°C Free-Air Temper		mpe	ratu	re (!	See I	Note	e 2)			•••	•	100 m
	rature:											
Continuous Power Dissipation at (or below) 25°C Free Air Temper	rature:		• •									150 m
Continuous Power Dissipation at (or below) 25 [°] C Free Air Temper Infrared-Emitting Diode (See Note 3) Phototransistor (See Note 4)	rature:	•	•••		•••			•				150 m 150 m
Continuous Power Dissipation at (or below) 25 ⁶ C Free Air Temper Infrared-Emitting Diode (See Note 3)	rature: te 5)		••••	•	· ·			•		 		150 mi 150 mi 250 mi

- 3. Derate linearly to 100° C free air temperature at the rate of 2 mW/ C 4. Derate linearly to 100° C free air temperature at the rate of 2 mW/ C
 - 5. Derate linearly to 100°C free air temperature at the rate of 3.33 mW/ C

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	PARAMETER		METER TEST CONDITIONS		TIL111 TIL114			TIL116			TIL117			UNIT
						TYP		MIN	TYP	MAX	MIN	түр	MAX	
Collector Base VIBR)CBO Breakdown Voltage		1	l _C = 10 μA, lμ = 0	1 _E = 0,	70			70			70			v
VIBR)CEO	Collector- Breakdow	-	l _C = 1 mA, l _F = 0	18 = 0'	30			30			30			v
V(BR)EBO	Emitter B Breakdow	1	le = 10μΑ, le = 0	I _C = 0,	7			,			7			v
I R	Input Diode Static Reverse Current		V _R = 3 V				10			10			10	μA
	On-State	Phototransistor			2	7		ļ			 			mA
IC(on)	Collector Current	Operation	V _{CE} = 10 V, t _B = 0					2	5		5	9		
	Guillent	Photodiode Operation	V _{CB} = 0.4 V, I _E = 0		7	20		7	20		7	20		μА
^I C(off)	Off-State Collector Current	Phototransistor Operation	VCE = 10 V, IB = 0	·		۱	50		1	50	T	1	50	
		Photodiode Operation	V _{CB} = 10 V, I _E = 0	1 F = 0'		01	20		0.1	20		0.1	20] "``
	Transistor		VCE = 5 V. I _F = 0	I _C = 10 mA.	100	300					200	550		
hFE	Forward (Transfer f		VCE = 5 V, IF = 0	,Aµ 100 ≃ _C I				100	300]
VF	Input Dio		1 _F = 16 mA		ţ	1.2	1.4		1,25	1.5	ļ	1.2	1.4	v
		vonage	ic = 2 mA, lg = 0	iç = 16 mA,		0.25	0.4		1.20	1.5				
V _{CE (sat})	Collector-Em Saturation Vo		1 _C = 2.2 mA, 1 _B = 0						0.25	04				v
			1 _C = 0.5 mA, 1 _B ∸ 0									0.25	04	
۲ID	Input-to-C Internal F	1		kV for TIL111, kV for all others,	1011			1013			1011			22
Cio	Input to C Capacitar	•	V _{in-out} = 0, See Note 6	t - 1 MHz,		1	13		1	1.3		1	1.3	pF

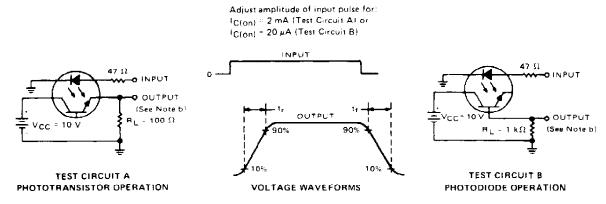
electrical characteristics at 25°C free-air temperature

NOTE 6. These parameters are measured between both input diode leads shorted together and all the phototransistor leads shorted together.

switching characteristics at 25°C free-air temperature

	PARAMETER		TEST CONDITIONS		TIL111 TIL114		TIL116			TIL117			UNIT
ļ					N TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	1
1 _r	Rise Time	Phototransistor	$V_{CC} = 10 V$, $I_{C(DD)} = 2 m A$		5	10	1	5	10		5	10	
ц.	Fall Time	Operation	R _L = 100 Ω, See Test Circuit A of Figure 1		5	10		5	10		5	10	μs
t _e	Rise Time	Photodiode	V _{CC} = 10 V, I _C (on) = 20 μ/	.	1			1		1	1		
tf	Fall Time	Operation	RL = 1 kΩ, See Test Circuit B of Figure 1		1			1			1		μs

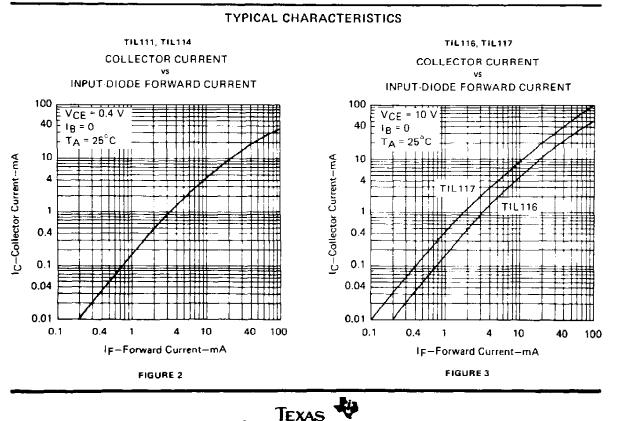




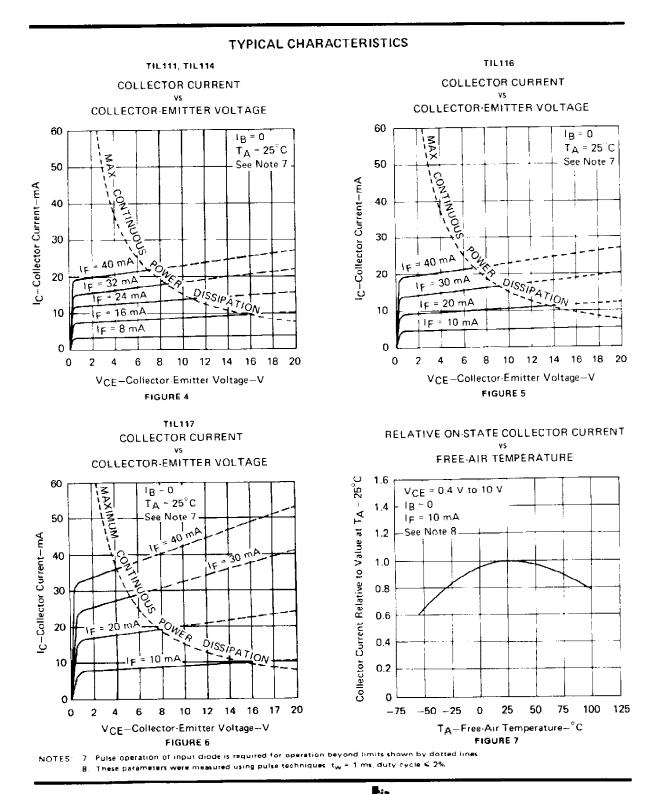
NOTES i.a. The input waveform is supplied by a generator with the following characteristics: Z_{out} = 50 Ω , t, f = 15 ns, duty cycle \approx 1%, I_w = 100 μ s

b. The output waveform is monitored on an oscilloscope with the following characteristics: $t_{\rm r} <$ 12 ns, R $_{
m in}$ in 1 MO, C $_{
m in}$ \lesssim 20 pF.

FIGURE 1-SWITCHING TIMES

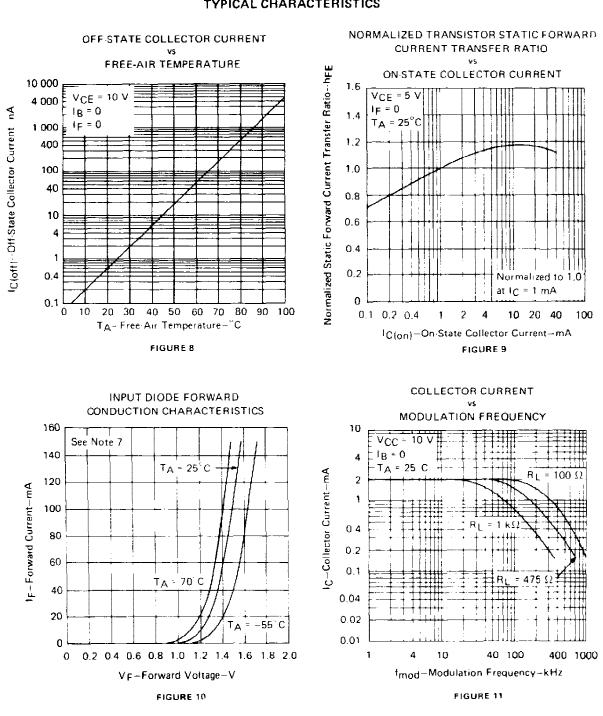


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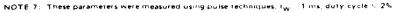


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TYPICAL CHARACTERISTICS





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Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TIL111	OBSOLETE	PDIP	Ν	6	TBD	Call TI	Call TI
TIL114	OBSOLETE	PDIP	Ν	6	TBD	Call TI	Call TI
TIL116	OBSOLETE	PDIP	Ν	6	TBD	Call TI	Call TI
TIL117	OBSOLETE	PDIP	N	6	TBD	Call TI	Call TI

⁽¹⁾ The marketing status values are defined as follows:

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⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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